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CONTENTS

15 APRIL 1997-II

RAPID COMMUNICATIONS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

- Observation of Fermi-liquid behavior in the two-dimensional Hubbard model for self-consistent perturbation theory R10 149
S. Wermbter
- Magneto-optical properties of U 5*f* electrons in U₃P₄ R10 153
J. Köhler, L. M. Sandratskii, and J. Kübler
- H₂O hydrogen bonding in density-functional theory R10 157
D. R. Hamann
- Proposed synthesis path for heterodiamond BC₂N R10 161
Y. Tateyama, T. Ogitsu, K. Kusakabe, S. Tsuneyuki, and S. Itoh
- Pauli susceptibility of A₃C₆₀ (A=K,Rb) R10 165
F. Aryasetiawan, O. Gunnarsson, E. Koch, and R. M. Martin
- Irrelevance in the (*d*−2) expansion of nonlinear σ and Heisenberg models R10 169
E. Brézin and S. Hikami
- Optical evidence of 4*f*-band formation in CeN R10 173
Anna Delin, P. M. Oppeneer, M. S. S. Brooks, T. Kraft, J. M. Wills, Börje Johansson, and Olle Eriksson

Semiconductors I: bulk

- Optical detection of magnetic resonance in electron-irradiated GaN R10 177
Matthias Linde, S. J. Uffring, G. D. Watkins, V. Härle, and F. Scholz
- Defect creation and removal in hydrogenated amorphous silicon predicted by the defect-pool model and revealed by the quasistatic capacitance of metal-insulator-semiconductor structures R10 181
J. P. Kleider and F. Dayoub
- Ballistic transport of holes and phonon replicas in lightly doped GaAs R10 185
D. Sprinzak, M. Heiblum, Y. Levinson, and Hadas Shtrikman

Semiconductors II: surfaces, interfaces, microstructures, and related topics

- Surface segregation in (Ga,In)As/GaAs quantum boxes R10 189
N. Grandjean, J. Massies, and O. Tottereau
- Semiclassical analysis of response functions for integrable systems R10 193
B. Mehlig
- Thermoelectric signature of the excitation spectrum of a quantum dot R10 197
A. S. Dzurak, C. G. Smith, C. H. W. Barnes, M. Pepper, L. Martín-Moreno, C. T. Liang, D. A. Ritchie, and G. A. C. Jones
- Theory of the breakdown of the quantum Hall effect R10 201
V. Tsemekhman, K. Tsemekhman, C. Wexler, J. H. Han, and D. J. Thouless
- Persistent current in an artificial quantum-dot molecule R10 205
R. Kotlyar and S. Das Sarma
- Ballistic electrons in an open square geometry: Selective probing of resonant-energy states R10 209
I. V. Zozoulenko, R. Schuster, K. -F. Berggren, and K. Ensslin



(Continued)

0163-1829(19970415)55:16;1-Z

High-temperature anomaly of the conductance of a tunnel junction	R10 213
Georg Göppert, Xiaohui Wang, and Hermann Grabert	
Characteristic scaling parameters for tunneling in strong time-dependent electric fields	R10 217
Mathias Wagner and W. Zwerger	
Stability of optically active charged excitons in quasi-two-dimensional systems	R10 221
James R. Chapman, Neil F. Johnson, and V. Nikos Nicopoulos	

Surface physics, low-dimensional systems, and related topics

Observation of metallic conductivity down to 14 K in Langmuir-Blodgett films based on BEDO-TTF and behenic acid	R10 225
Hitoshi Ohnuki, Tetsuya Noda, Mitsuru Izumi, Tatsuro Imakubo, and Reizo Kato	
Role of the step curvature in the stabilization of coherently strained epitaxial structures	R10 229
P. Krapf, Y. Robach, M. Gendry, and L. Porte	
Effects of hydrogen in Ni(100) submonolayer homoepitaxy	R10 233
Kenneth Haug, Zhenyu Zhang, David John, Curtis F. Walters, David M. Zehner, and Ward E. Plummer	
Sublimation of the Si(111) surface in ultrahigh vacuum	R10 237
Yoshikazu Homma, Hiroki Hibino, Toshio Ogino, and Noriyuki Aizawa	
Growth and characterization of vapor-deposited polyaniline on Cu(110)	R10 241
R. V. Plank, N. J. DiNardo, and J. M. Vohs	
First-principles study on B ₁₂ clusters in Si	R10 245
Jun Yamauchi, Nobutoshi Aoki, and Ichiro Mizushima	

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Band structure and transport properties of CrO ₂	10 253
Steven P. Lewis, Philip B. Allen, and Taizo Sasaki	
Spontaneous lattice deformation in the Hofstadter system	10 261
Takeshi Honda and Tetsuji Tokihiro	
Two-site Hubbard model, the Bardeen-Cooper-Schrieffer model, and the concept of correlation entropy	10 270
Paul Ziesche, Olle Gunnarsson, Walter John, and Hans Beck	
<i>Ab initio</i> calculation of the quasiparticle spectrum and excitonic effects in Li ₂ O	10 278
Stefan Albrecht, Giovanni Onida, and Lucia Reining	
Quantum chemical approach to cohesive properties of NiO	10 282
Klaus Doll, Michael Dolg, Peter Fulde, and Hermann Stoll	
Adaptive-coordinate real-space electronic-structure calculations for atoms, molecules, and solids	10 289
N. A. Modine, Gil Zumbach, and Efthimios Kaxiras	
Effect of layer-thickness randomness on gap solitons and optical bistability in nonlinear superlattices with photonic stop gaps	10 302
Zhi-Yong Zhang and Shi-Jie Xiong	
Landauer conductance in the diffusive regime	10 308
X.-G. Zhang and W. H. Butler	
Numerical study of the current instability in a two-dimensional electron fluid	10 319
A. P. Dmitriev, A. S. Furman, V. Yu. Kachorovskii, G. G. Samsonidze, and Ge. G. Samsonidze	
Local-field effects in nonlinear dielectrics	10 326
M. A. Palenberg and B. U. Felderhof	
First-principles responses of solids to atomic displacements and homogeneous electric fields: Implementation of a conjugate-gradient algorithm	10 337
Xavier Gonze	

Dynamical matrices, Born effective charges, dielectric permittivity tensors, and interatomic force constants from density-functional perturbation theory	10 355
Xavier Gonze and Changyol Lee	
Calculation of energy levels and polarized oscillator strengths for Nd ³⁺ :YAG	10 369
Mattias Klintonberg, Sverker Edvardsson, and John O. Thomas	
Hybridization of the 3d states of transition metals with the states of the ZnS matrix	10 376
K. Lawniczak-Jablonska, R. C. C. Perera, J. H. Underwood, E. M. Gullikson, and R. J. Iwanowski	
Ti and O K edges for titanium oxides by multiple scattering calculations: Comparison to XAS and EELS spectra	10 382
Z. Y. Wu, G. Ouvrard, P. Gressier, and C. R. Natoli	
Electronic structure of WSe ₂ : A combined photoemission and inverse photoemission study	10 392
M. Traving, M. Boehme, L. Kipp, M. Skibowski, F. Starrost, E. E. Krasovskii, A. Perlov, and W. Schattke	
Occupied and unoccupied electronic band structure of WSe ₂	10 400
Th. Finteis, M. Hengsberger, Th. Straub, K. Fauth, R. Claessen, P. Auer, P. Steiner, S. Hufner, P. Blaha, M. Vögt, M. Lux-Steiner, and E. Bucher	
Two-dimensional XXZ model ground-state properties using an analytic Lanczos expansion	10 412
N. S. Witte, Lloyd C. L. Hollenberg, and Zheng Weihong	
High-resolution Fourier-transform spectroscopy of solid parahydrogen in the first overtone region	10 420
Markus Mengel, Brenda P. Winnewisser, and Manfred Winnewisser	
Absolute band gaps and electromagnetic transmission in quasi-one-dimensional comb structures	10 434
J. O. Vasseur, P. A. Deymier, L. Dobrzynski, B. Djafari-Rouhani, and A. Akjouj	
Far-infrared transmittance and band-structure correspondence in two-dimensional air-rod photonic crystals	10 443
Mitsuo Wada, Yoshiyuki Doi, Kuon Inoue, and J. W. Haus	
Statistics of rare events in disordered conductors	10 451
Igor E. Smolyarenko and Boris L. Altshuler	
Semiconductors I: bulk	
Defects in electron-irradiated GaAs studied by positron lifetime spectroscopy	10 467
A. Polity, F. Rudolf, C. Nagel, S. Eichler, and R. Krause-Rehberg	
Defects in electron-irradiated InP studied by positron lifetime spectroscopy	10 480
A. Polity and T. Engelbrecht	
Biexciton-biexciton interaction in semiconductors	10 487
Hoang Ngoc Cam	
Generation of vacancy-type point defects in single collision cascades during swift-ion bombardment of silicon	10 498
B. G. Svensson, C. Jagadish, A. Hallén, and J. Lalita	
<i>Ab initio</i> total-energy calculations for iron-acceptor pairs in silicon	10 508
H. Overhof and H. Wehrich	
Pressure-induced shallow donor transformations in gallium arsenide	10 515
Leonardo Hsu, S. Zehender, E. Bauser, and E. E. Haller	
Effect of spin-glass order on magnetic polarons in semimagnetic semiconductors	10 519
A. L. Chudnovskiy, R. Oppermann, B. Rosenow, D. R. Yakovlev, U. Zehnder, and W. Ossau	
Transient photoconductivity with optical bias in undoped and slightly <i>n</i> -doped hydrogenated amorphous silicon ...	10 528
P. Pipoz, H. Beck, and A. V. Shah	
Role of deep-level trapping on the surface photovoltage of semi-insulating GaAs	10 541
Qiang Liu and Harry E. Ruda	

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Influence of defects on the order-disorder phase transition of a Si(001) surface	10 549
Yoshimichi Nakamura, Hiroshi Kawai, and Masatoshi Nakayama	
<i>Ab initio</i> calculations of structural and electronic properties of 6H-SiC(0001) surfaces	10 561
Magdalena Sabisch, Peter Krüger, and Johannes Pollmann	
Electron parametric resonance in a two-dimensional electron gas	10 571
Miguel Calvo	
Quantum size effects of charge-transfer excitons in nonpolar molecular organic thin films	10 578
Zilan Shen and Stephen R. Forrest	
Scaling and crossover functions for the conductance in the directed network model of edge states	10 593
Ilya A. Gruzberg, N. Read, and Subir Sachdev	
Quantum Hall transition in an array of quantum dots	10 602
K. Ziegler	
Spin polarization of two-dimensional electrons in different fractional states and around filling factor $\nu=1$	10 607
I. V. Kukushkin, K. v. Klitzing, and K. Eberl	
Exciton magnetic polaron in semimagnetic semiconductor nanocrystals	10 613
A. K. Bhattacharjee and C. Benoit à la Guillaume	
Enhancement of electron-phonon interaction in ultrashort-period GaAs/AlAs superlattices	10 621
V. G. Litovchenko, D. V. Korbutyak, S. Krylyuk, H. T. Grahn, and K. H. Ploog	
Delocalization in continuous disordered systems	10 625
M. Hilke and J. C. Flores	
Spin precession and time-reversal symmetry breaking in quantum transport of electrons through mesoscopic rings	10 631
Ya-Sha Yi, Tie-Zheng Qian, and Zhao-Bin Su	
Coulomb blockade threshold in inhomogeneous one-dimensional arrays of tunnel junctions	10 638
J. A. Melsen, Ulrik Hanke, H.-O. Müller, and K.-A. Chao	
Quantum Hall effect in single wide quantum wells	10 643
M. Abolfath, L. Belkhir, and N. Nafari	
Statistics of Skyrmions and the $\nu=5/2$ puzzle	10 654
Jacek Dziarmaga	
Scaling behavior and universality near the quantum Hall transition	10 661
K. Ziegler	
Hartree-Fock theory of Skyrmions in quantum Hall ferromagnets	10 671
H. A. Fertig, Luis Brey, R. Côté, A. H. MacDonald, A. Karlhede, and S. L. Sondhi	
Nonlinear transport in GaAs/AlAs harmonically confined quantum wires	10 681
I. C. da Cunha Lima, X.-F. Wang, and X. L. Lei	
Effect of the Stark confinement on the excitonic optical spectrum of an array of coupled quantum dots	10 688
M. Pacheco and Z. Barticevic	
Depletion-electric-field-induced second-harmonic generation near oxidized GaAs(001) surfaces	10 694
Thomas A. Germer, Kurt W. Kołasiński, John C. Stephenson, and Lee J. Richter	
Effects of acoustic-mode localization under dimensional crossover of an electron gas	10 707
V. A. Kochelap and V. V. Mitin	
Effects of applied electric fields on the infrared transitions between hydrogenic states in GaAs low-dimensional systems	10 721
C. A. Duque, A. L. Morales, A. Montes, and N. Porras-Montenegro	
Spin splitting in a <i>p</i> -type quantum well with built-in electric field and microscopic inversion asymmetry	10 729
O. Mauritz and U. Ekenberg	

Charge transport and magnetic properties in polyaniline doped with methane sulphonic acid and polyaniline-polyurethane blend	10 734
B. Sanjai, Anasuya Raghunathan, T. S. Natarajan, G. Rangarajan, Solomon Thomas, P. V. Prabhakaran, and S. Venkatachalam	
Semiclassical description of electron transport in semiconductor quantum-well devices	10 745
G. A. Baraff	
Aharonov-Bohm oscillations with fractional period in a multichannel Wigner crystal ring	10 754
I. V. Krive and A. A. Krokhin	
Optical properties of Si_mGe_n superlattices: A CPA treatment of the interface diffusion	10 760
I. A. Papadogonas, A. N. Andriotis, and E. N. Economou	
Surface physics, low-dimensional systems, and related topics	
Atomic-force-microscope study of contact area and friction on NbSe_2	10 776
M. A. Lantz, S. J. O'Shea, M. E. Welland, and K. L. Johnson	
X-ray study of the oxidation of liquid-gallium surfaces	10 786
M. J. Regan, H. Tostmann, P. S. Pershan, O. M. Magnussen, E. DiMasi, B. M. Ocko, and M. Deutsch	
hcp-to-fcc stacking switch in thin cobalt films induced by Cu capping	10 791
Ch. Rath, J. E. Prieto, S. Müller, R. Miranda, and K. Heinz	
Direct observation of atom movement in photoexcited ionic-electronic conductors	10 800
Yasushi Utsugi	
<i>Ab initio</i> study of the CoSi_2 (110) surface	10 805
Doris Vogtenhuber and Raimund Podloucky	
Bond counting in a simulation model of epitaxial growth	10 814
Michael Schroeder, Pavel Šmilauer, and Dietrich E. Wolf	
Interaction of silane with $\text{Cu}(111)$: Surface alloy and molecular chemisorbed phases	10 819
N. J. Curson, H. G. Bullman, J. R. Buckland, and W. Allison	
Structure determination of chemisorbed $c(2 \times 2)\text{P}/\text{Fe}(100)$ using angle-resolved photoemission extended fine structure and self-consistent-field $X\alpha$ scattered-wave calculations: Comparison with $c(2 \times 2)\text{S}/\text{Fe}(100)$	10 830
W. R. A. Huff, Y. Chen, X. S. Zhang, L. J. Terminello, F. M. Tao, Y. K. Pan, S. A. Kellar, E. J. Moler, Z. Hussain, H. Wu, Y. Zheng, X. Zhou, A. E. Schach von Wittenau, S. Kim, Z. Q. Huang, Z. Z. Yang, and D. A. Shirley	
Dispersions of surface states on diamond (100) and (111)	10 841
R. Graupner, M. Hollering, A. Ziegler, J. Ristein, L. Ley, and A. Stampfl	
Halogen adsorption on transition-metal surfaces: A case study of Cl on $\text{Ta}(110)$	10 848
Christine J. Wu and John E. Klepeis	
Comparative study of <i>K</i> -shell exciton series in condensed neon and nitrogen by electron time-of-flight spectroscopy	10 854
B. Kassühlke, P. Averkamp, S. Frigo, P. Feulner, and W. Berthold	
Impurity resistivity of an ideal metallic thin film	10 863
Zhongcheng Wang, Shaofeng Wang, Songhua Shen, and Shichang Zhou	
Hot-electron dynamics at $\text{Cu}(100)$, $\text{Cu}(110)$, and $\text{Cu}(111)$ surfaces: Comparison of experiment with Fermi-liquid theory	10 869
S. Ogawa, H. Nagano, and H. Petek	
Local characterization of transmission properties of a two-dimensional photonic crystal	10 878
Eric B. McDaniel, J. W. P. Hsu, Lori S. Goldner, R. J. Tonucci, Eric L. Shirley, and Garnett W. Bryant	
Modified self-consistent approach applied in near-field optics for mesoscopic surface defects	10 883
Zhiyuan Li, Benyuan Gu, and Guozhen Yang	
EELS study of the clean and hydrogen-covered $\text{Mo}(110)$ surface	10 895
J. Kröger, S. Lehwald, and H. Ibach	

CONTENTS - *Continued*

PHYSICAL REVIEW B

THIRD SERIES, VOLUME 55, NUMBER 16

15 APRIL 1997-II

Structure and properties of cobalt clusters up to the tetramer: A density-functional study	10 905
Christine Jamorski, Ana Martinez, Miguel Castro, and Dennis R. Salahub	
Calculation of the dielectric constant of monolayer films with dielectric anisotropy	10 922
Chen-Xu Wu and Mitsumasa Iwamoto	
Microstructure of the surfactantlike effect in Ni/Ag(100) and (111)	10 931
Jean-Marc Roussel, Andrés Saúl, Guy Trégliá, and Bernard Legrand	
Electronic structure of quasicrystals studied by ultrahigh-energy-resolution photoemission spectroscopy	10 938
Z. M. Stadnik, D. Purdie, M. Garnier, Y. Baer, A.-P. Tsai, A. Inoue, K. Edagawa, S. Takeuchi, and K. H. J. Buschow	
Hydrogen transport in nickel (111)	10 952
Roi Baer, Yehuda Zeiri, and Ronnie Kosloff	
Cumulative Author Index	10 975